

What is claimed is:

1. A semiconductor dynamic quantity sensor comprising:
a support substrate having an opening portion open on a surface thereof;

first and second movable electrode supporting portions fixed to the support substrate;

a movable electrode supported by the first and second movable electrode supporting portions to be displaced in accordance with a dynamic quantity applied thereto;

first and second fixed electrode supporting portions fixed to the support substrate; and

a fixed electrode supported by the first and second fixed electrode supporting portions and facing the movable electrode with a detection interval defined therebetween, the detection interval being changed to detect the dynamic quantity when the movable electrode is displaced,

wherein the first and second movable electrode supporting portions are provided on opposed sides of the opening portion; and

the first and second fixed electrode supporting portions are provided on the opposed sides of the opening portion.

2. The semiconductor dynamic quantity sensor according to claim 1, wherein an axis connecting the first and second movable electrode supporting portions is approximately parallel to an axis connecting the first and second fixed electrode supporting portions.

3. The semiconductor dynamic quantity sensor according to claim 1, wherein the opening portion is generally rectangular.

4. The semiconductor dynamic quantity sensor according to claim 1, wherein:

the movable electrode has a weight portion that is connected to the first and second movable electrode supporting portions at both ends thereof, and has a pole portion protruding from the weight portion;

the fixed electrode has a connecting portion that is connected to the first and second fixed electrode supporting portions at both ends thereof, and has a pole portion protruding from the connecting portion and having a side face facing a side face of the pole portion of the movable electrode.

5. The semiconductor dynamic quantity sensor according to claim 4, wherein the connecting portion of the fixed electrode has a bent portion that is bent to extend toward one of the first and second movable electrode supporting portions.

6. The semiconductor dynamic quantity sensor according to claim 4, wherein:

the fixed electrode has two pole portions respectively protruding from the connecting portion; and

the connecting portion is widened at a portion connecting the two pole portions.

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T05050 T2052660

7. A semiconductor dynamic quantity sensor comprising:
a support substrate having an opening portion open on a surface thereof;

first and second movable electrode supporting portions fixed to the support substrate;

a movable electrode supported by the first and second movable electrode supporting portions to be displaced in a displacement direction in accordance with a dynamic quantity applied thereto;

first and second fixed electrode supporting portions fixed to the support substrate; and

a fixed electrode supported by the first and second fixed electrode supporting portions and facing the movable electrode with a detection interval defined therebetween, the detection interval being changed to detect the dynamic quantity when the movable electrode is displaced,

wherein the first and second movable electrode supporting portions are arranged in a direction approximately parallel to a direction in which the first and second fixed electrode supporting portions are arranged.

8. The semiconductor dynamic quantity sensor according to claim 7, wherein the direction in which the first and second movable electrode supporting portions and the first and second fixed electrode supporting portions are respectively arranged is approximately parallel to the displacement direction of the

a detection surface facing the detection surface of the movable electrode while defining a detection interval that is changed to detect the dynamic quantity when the movable electrode is displaced by the dynamic quantity,

wherein a width of the frame member in the displacement direction of the movable electrode is uniform.

12. The semiconductor dynamic quantity sensor according to claim 11, wherein the frame member is bonded to a base portion through adhesive having a thermal expansion coefficient different from that of the frame member.

13. The semiconductor dynamic quantity sensor according to claim 11, wherein the movable electrode is symmetrical with respect to a centerline of the frame member.

14. The semiconductor dynamic quantity sensor according to claim 11, wherein:

the fixed electrode is composed of a first fixed electrode and a second fixed electrode that are disposed at both sides of the movable electrode and respectively produce a first capacitance and a second capacitance with the movable electrode;

the first capacitance changes in a different direction from that of the second capacitance when the movable electrode is displaced so that a differential capacitance between the first capacitance and the second capacitance is outputted to detect the dynamic quantity; and

a first portion of the frame member supporting the first fixed electrode has a width that is approximately equal to that of a second portion of the frame member supporting the second fixed electrode.

15. The semiconductor dynamic quantity sensor according to claim 11, wherein:

the fixed electrode is composed of first and fixed electrodes that are disposed at both sides of the movable electrode;

each of the first and second fixed electrodes has a supporting portion fixed to the frame member and a comb-shaped electrode portion extending from the supporting portion toward the movable electrode; and

the supporting portion of the first fixed electrode and the supporting portion of the second fixed electrode are point-symmetrical with respect to a center of the frame member.

16. The semiconductor dynamic quantity sensor according to claim 11, wherein the frame member is square.

17. The semiconductor dynamic quantity sensor according to claim 11, wherein the frame member has a first frame part supporting an end of the movable electrode and a second frame part supporting another end of the movable electrode; and

the first frame part has a width in the displacement direction that is approximately equal to that of the second frame part.